

# **Dual N-Channel 20-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
20	0.019 at V <sub>GS</sub> = 4.5 V	7.1		
20	0.026 at V <sub>GS</sub> = 2.5 V	6.0		

#### **FEATURES**

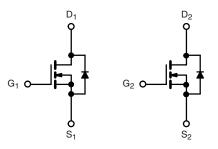
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> Tested
- Compliant to RoHS Directive 2002/95/EC







Top View



N-Channel MOSFET

N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise not	ed	
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V <sub>DS</sub>	20	
Gate-Source Voltage		$V_{GS}$	± 12	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	ı	7.1	
	T <sub>A</sub> = 70 °C	I <sub>D</sub>	5.7	•
Pulsed Drain Current (10 µs Pulse Width)		I <sub>DM</sub>	40	A
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	1.7	
M · D D · · · · · · · · · · · · · · · ·	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2	١٨/
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	FD —	1.3	W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stq</sub>	- 55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Maximum Junction-to-Ambient <sup>a</sup>	R <sub>thJA</sub>	62.5	°C/W		

#### Notes

a. Surface Mounted on FR4 board,  $t \le 10 \text{ s.}$ 



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•				
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.5	V	
Gate-Body Leakage	I <sub>GSS</sub>				± 100	nA	
Zava Cata Valtaga Dvais Current	1	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			1	1 5 μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	20			Α	
	В	$V_{GS} = 4.5 \text{ V}, I_D = 7.1 \text{ A}$		0.019		0	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 6.0 \text{ A}$		0.026		Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_D = 7.1 \text{ A}$		27		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 1.7 A, V <sub>GS</sub> = 0 V			1.2	٧	
Dynamic <sup>b</sup>			•				
Total Gate Charge	Qg			9.5			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 7.1 \text{ A}$		1.5		nC	
Gate-Drain Charge	$Q_{gd}$			2.5		7	
Gate Resistance	$R_g$	f = 1 MHz		1.6	2.7	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			10			
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		15			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong 1$ A, $V_{GEN}=4.5$ V, $R_g=10\Omega$		38		ns	
Fall Time	t <sub>f</sub>			25			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.7 A, dI/dt = 100 A/μs		26			

#### Notes:

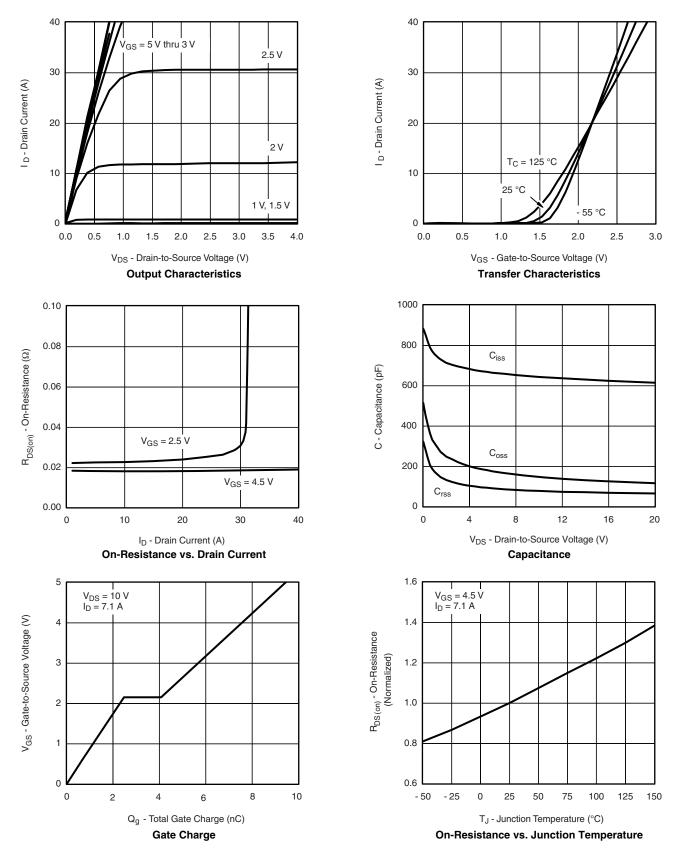
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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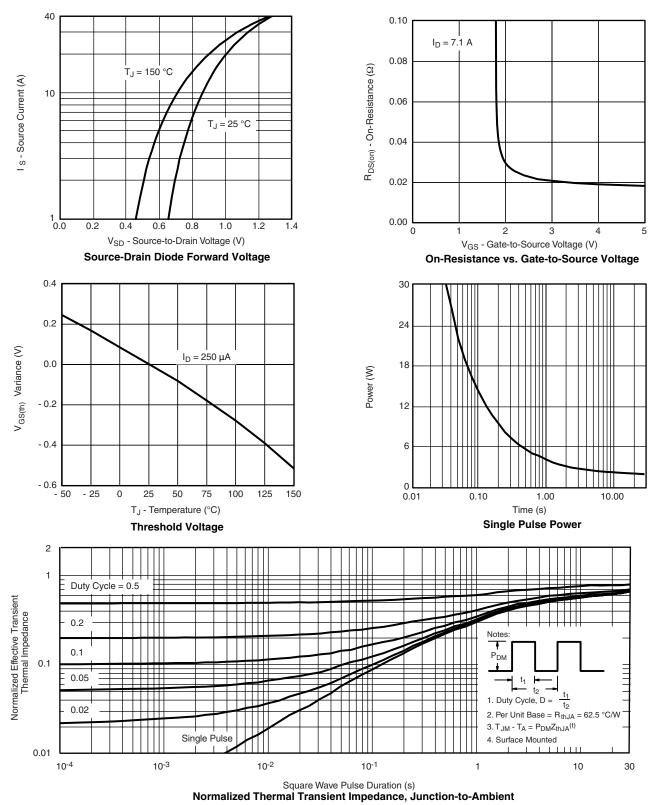


## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





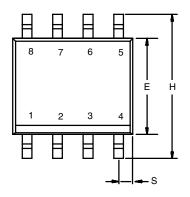
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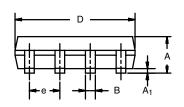


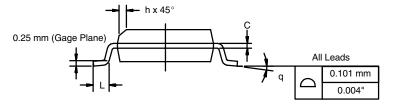
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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







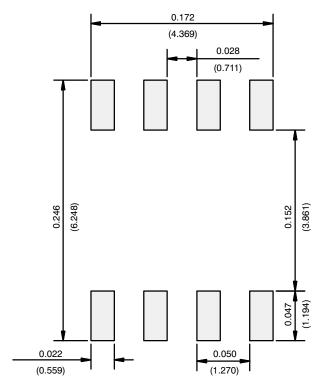
	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27 BSC		0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06						

DWG: 5498

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### **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)

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